## NSN 5961-01-176-3397

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View Online at https://aerobasegroup.com/nsn/5961-01-176-3397 **Inclosure Material:** Metal **Overall Length:** 12.063 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-118 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.750 inches **Thread Size:** 0.750 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 off-state voltage, dc **Current Rating Per Characteristic:** 400.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector not applicable **Special Features:** Item must comply with requirements of defense supply center columbus production standard no. Lo3321; junction pattern arrangement: pnpnp **Thread Series Designator: Terminal Type And Quantity:** 3 tab, solder lug and 1 threaded stud **Reference Number Differentiating Characteristics:** Areference number differentiating material will be in accordance with naval inventory control point activity hx quality control. Manufacturing and testing specifications available at the dla icp Shelf Life: N/a **Unit Of Measure:** 

No

**Demilitarization:** 

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